

MLCC(Multilayer Ceramic Capacitor) is SMD(Surface Mounted Device) type capacitor that is used in wide ranges of capacitance. MLCC is paid more attentions than other capacitors due to the better frequency characteristics, higher reliability, higher withstanding voltage and so on.

MLCC is made of many layers of ceramic and inner electrodes like sandwich. Pd was used for inner electrodes. But the price of Pd was skyrocketed and Pd was replaced by the BME(Base Metal Electrode), which reduced the total cost of MLCC.

This inner electrode is connected to outer termination for surface mounting, which is composed of three layers, Cu or Ag layer, Ni plating layer, and SnPb or Sn plating layer. Most of MLCCs become Pb free by the environmental issue at present.

MLCC is divided into two classes. Class I(C0G, etc) is the temperature compensating type. It has a small TCC(Temperature Coefficient of Capacitance) and a better frequency performance. Therefore, it is used in RF applications such as cellular phone, tuner, and so on. Class II(X7R, X5R, Y5V, etc) is the high dielectric constant type, which is used in general electronic circuit. Especially high capacitance MLCC is replacing other capacitors (Tantalum and Aluminum capacitor) due to the low ESR(Equivalent Series Resistance) value.

■ FEATURE AND APPLICATION

• Feature

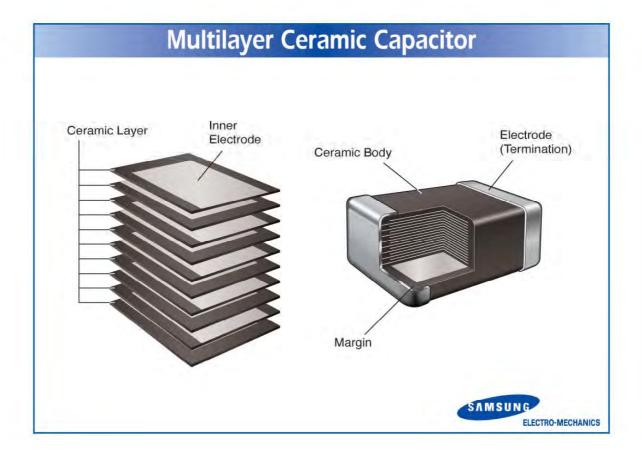
- Miniature Size
- Wide Capacitance and Voltage Range
- Highly Reliable Performance
- Tape & Reel for Surface Mount Assembly
- Low ESR
- High Q at High Frequencies
- Stable Temperature Dependence of Capacitance

• Application

- High Frequency Circuit(Tuner, VCO, PAM etc)
- General Power Supply Circuit(SMPS etc)
- DC-DC Converter
- General Electronic Circuit

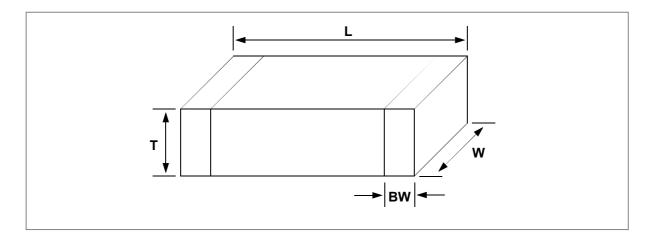


STRUCTURE





■ APPEARANCE AND DIMENSION



CODE	EIA CODE		ON (mm)		
CODL		L	W	T (MAX)	BW
03	0201	$0.6~\pm~0.03$	$0.3~\pm~0.03$	$0.3~\pm~0.03$	0.15±0.05
05	0402	$1.0~\pm~0.05$	$0.5~\pm~0.05$	$0.5~\pm~0.05$	0.2+0.15/-0.1
10	0603	1.6 ± 0.1	$0.8~\pm~0.1$	$0.8~\pm~0.1$	0.3 ± 0.2
21	0805	$2.0~\pm~0.1$	$1.25~\pm~0.1$	1.25± 0.1	0.5+0.2/-0.3
31	1206	3.2 ± 0.2	$1.6~\pm~0.2$	$1.6~\pm~0.2$	0.5+0.2/-0.3
32	1210	3.2 ± 0.3	2.5 ± 0.2	$2.5~\pm~0.2$	0.6 ± 0.3
43	1812	$4.5~\pm~0.4$	3.2 ± 0.3	3.2 ± 0.3	0.8 ± 0.3
55	2220	$5.7~\pm~0.4$	$5.0~\pm~0.4$	3.2 ± 0.3	1.0 ± 0.3

■ PREVIOUS PART NUMBERING



- SAMSUNG Multilayer Ceramic Capacitor
- Type(Size)
- Capacitance Temperature Characteristics
- Nominal Capacitance
- Capacitance Tolerance
- Rated Voltage
- Thickness Option
- Packaging Type

CAPACITANCE TEMPERATURE CHARACTERISTICS

CLASS I (Temperature Compensation)

Symbol	EIA Code	Temperature Coefficient(PPM/℃)	TemperatureCharacteristics	Operation Temperature Range
С	C0G(CH)	0 ± 30	CΔ	
Р	P2H	-150 ± 60	PΔ	
R	R2H	-220 ± 60	R∆	
S	S2H	-330 ± 60	S∆	-55 ~ +125℃
Т	T2H	-470 ± 60	TΔ	
U	U2J	-750 ± 120	UΔ	
L	S2L	+350 ~ -1000	SL	

<u>* Temperature Characteristics</u>

Temperature Characteristics	below 2.0pF	2.2 ~ 3.9pF	above 4.0pF	above 10pF	
C∆	C0G	C0G	C0G	C0G	_
Р∆	-	P2J	P2H	P2H	_
R∆	-	R2J	R2H	R2H	☞ K:±250 PPM/℃
S∆	-	S2J	S2H	S2H	J : ±120 PPM/℃
ТΔ	-	T2J	T2H	T2H	H : ±60 PPM/℃
UΔ	-	U2J	U2J	U2J	G : ±30 PPM/°C

► CLASS II (High Dielectric Constant)

Symbol	EIA Code	Capacitance Change (∆C : %)	Operation Temperature Range
Α	X5R	± 15	-55 ~ +85℃
В	X7R	± 15	-55 ~ +125℃
F	Y5V	+22 ~ -82	-30 ~ +85℃



NOMINAL CAPACITANCE

The nominal capacitance value is expressed in pico-Farad(pF) and identified by threedigit number, first two digits represent significant figures and last digit specifies the number of zeros to follow. For values below 1pF, the letter "R" is used as the decimal point and the last digit becomes significant.

examp	ole)			
100 :	10 \times	10° =	10pF	
102 :	10 $ imes$	10 ² =	1000pF	
020 :	2 ×	10° =	2pF	
1R5 :	1.5pF	-		

Temperature Characteristics	Symbol	Tolerance	Applicable Capacitance & Range
	В	± 0.1pF	0.5 ~ 3pF
	С	± 0.25pF	0.5 40-5
C0G(NPO)	D	± 0.5pF	– 0.5 ~ 10pF
or	F	± 1pF	6 ~ 10pF
T.C Series	G	± 2%	
	J	± 5%	E-24 Series for over 10pF
	К	± 10%	
	J	± 5%	
A(X5R) B(X7R)	К	± 10%	E-12 Series
	М	± 20%	
F(Y5V)	Z	-20% ~ +80%	E-6 Series

CAPACITANCE TOLERANCE

* Please consult us for special tolerances.

RATED VOLTAGE

Symbol	Rated Voltage(Vdc)	Symbol	Rated Voltage(Vdc)
Q	6.3V	D	200V
Р	10V	G	500V
0	16V	l	1000V
Α	25V	J	2000V
В	50V	К	3000V
С	100V		

THICKNESS OPTION

Symbol	Description of the Code			
Ν	Standard thickness (please refer to standard thickness table on next page)			
Α	Thinner than standard thickness			
В	Thicker than standard thickness			
С	Standard Thickness High Q (Low ` D.F `)			
D	Sn-100% (High-Q)			
E	Sn-100% (General)			

* Please Consult us for other termination type.

PACKAGING TYPE

Symbol	Packaging	Symbol	Packaging
В	Bulk	F	Embossed Tape, 13" Reel
Р	Cassette	L	Paper 13" Reel
С	Paper Tape, 7" Reel	0	Paper 10" Reel
D	Paper Tape, 13" Reel	S	Embossed Tape, 10" Reel
Е	Embossed Tape, 7" Reel		

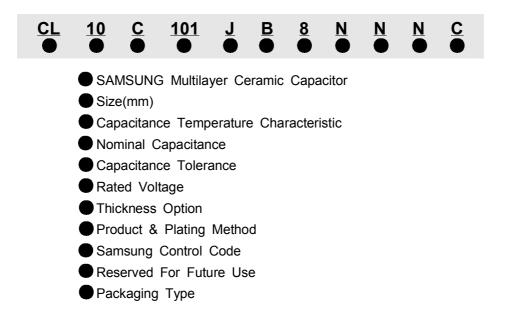
► STANDARD CAPACITANCE STEP

Series		Capacitance Step										
E- 3	1.0			2.2			4.7					
E- 6	1	.0	1	.5	2	.2	3	.3	4	.7	6	.8
E-12	1.0	1.2	1.5	1.8	2.2	2.7	3.3	3.9	4.7	5.6	6.8	8.2
F 04	1.0	1.2	1.5	1.8	2.2	2.7	3.3	3.9	4.7	5.6	6.8	8.2
E-24	1.1	1.3	1.6	2.0	2.4	3.0	3.6	4.3	5.1	6.2	7.5	9.1

* Standard Capacitance is " Each step ×10" "



■ NEW PART NUMBERING



PRODUCT ABBREVIATION

Symbol	Product Abbreviation			
CL	SAMSUNG Multilayer Ceramic Capacitor			

• SIZE(mm)

Symbol	Size(mm)					
Symbol	Length	Width				
03	0.6	0.3				
05	1.0	0.5				
10	1.6	0.8				
21	2.0	1.2				
31	3.2	1.6				
32	3.2	2.5				
43	4.5	3.2				
55	5.7	5.0				



Symbol		Temperature Range					
С		COG	CA	0±30(ppm/℃)			
Р		P2H	PA	-150±60			
R		R2H RA		-220±60			
S	Class I	S2H	SA	-330±60	- 55 ∼ +125 ℃		
Т		T2H	ΤΔ	-470±60	-		
U		U2J	UA	-750±60			
L		S2L S△ +350 ~ -1000		+350 ~ -1000	-		
Α		X5R X5R ±15%		±15%	-55 ~ +85℃		
В	Class II	X7R	X7R	±15%	-55 ~ +125℃		
F]	Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃		

• CAPACITANCE TEMPERATURE CHARACTERISTIC

***** Temperature Characteristic

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF	
C∆	C0G	C0G	C0G	C0G	
PΔ	-	P2J	P2H	P2H	
R∆	-	R2J	R2H	R2H	
S∆	-	S2J	S2H	S2H	
ТΔ	-	T2J	T2H	T2H	
UΔ	-	U2J	U2J	U2J	

J : ±120PPM/℃, H : ±60PPM/℃, G : ±30PPM/℃

• NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance. The third digit identifies the multiplier. 'R' identifies a decimal point.

• Example

Symbol	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 µ F
104	100,000pF, 100nF, 0.1 µ F

SAMSUNG

	CAPACITANCE TOLERANCE										
Symbol	Tolerance	Nominal Capacitance									
Α	±0.05pF										
В	±0.1pF										
С	±0.25pF	Less than 10pF (Including 10pF)									
D	\pm 0.5pF	(including topi)									
F	±1pF										
F	±1%										
G	±2%										
J	±5%	More then 10pE									
К	±10%	More than 10pF									
м	±20%										
Z	+80, -20%										

RATED VOLTAGE

Symbol	Rated Voltage	Symbol	Rated Voltage		
Q	6.3V	E	250V		
Р	10V	G	500V		
0	16V	Н	630V		
Α	25V	I	1,000V		
В	50V	J	2,000V		
С	100V	К	3,000V		
D	200V	-			

THICKNESS OPTION

Туре	Symbol	Thickness(T)	Spec	
0603	3	0.30	±0.03	
1005	5	0.50	±0.05	
1608	8	0.80	±0.10	
	Α	0.65	0.40	
2012	С	0.85	±0.10	
	F	1.25	±0.10	
	С	0.85	±0.15	
3216	F	1.25	±0.15	
	н	1.6	±0.20	
	F	1.25		
2225	н	1.6		
3225	I	2.0	±0.20	
	J	2.5		
	F	1.25		
	н	1.6		
4532	I	2.0	±0.20	
	J	2.5		
	L	3.2	±0.30	
	F	1.25		
	н	1.6	+0.00	
5750	I	2.0	±0.20	
	J	2.5		
	L	3.2	±0.30	

	PRODUCT & PLATING METHOD													
Symbol	Electrode	Termination	Plating Type											
Α	Pd	Ag	Sn_100%											
N	Ni	Cu	Sn_100%											
G	Cu	Cu	Sn_100%											

SAMSUNG CONTROL CODE

Symbol	Description of the code	Symbol	Description of the code		
Α	Array (2-element)	N	Normal		
В	Array (4-element)	Р	Automotive		
С	High - Q	W	3 Terminal EMI Filter		
L	LICC				

RESERVED FOR FUTURE USE

Symbol	Description of the code
N	Reserved for future use

PACKAGING TYPE

Symbol	Packaging Type	Symbol	Packaging Type				
В	Bulk	F	Embossing 13" (10,000EA)				
Р	Bulk Case	Bulk Case					
С	Paper 7"	0	Paper 10"				
D	Paper 13" (10,000EA)	S	Embossing 10"				
E	Embossing 7"						

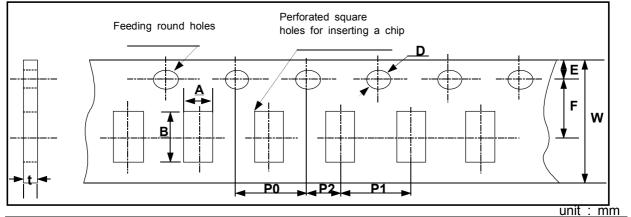


► CAPACITANCE vs CHIP THICKNESS STANDARD

De	escripti	on	0603 (0201)	1005 (0402)	1608 (0603)	20	12 Ty (0805	/pe)	32	216 Ty (1206	/pe)		3228 (1	5 Type 210)		4532 Type (1812)		5750 Type (2220)		ype 0)				
	L		0.6 ±0.03	1.0 ±0.05	1.6 ±0.1		2.0±0.′	1	3.2±	3.2±0.15		.2±0.15 3.2 ±0.2		3.2±0.3			4.5±0.4					5.7±0.4		
Dim (I	ension mm)	w	0.3 ±0.03	0.5 ±0.05	0.8 ±0.1		1.25±0.	1	1.6±	0.15	1.6 ±0.2	2.5±0.2				3.2	±0.3		5.0±0.4					
	т			0.5~ ±0.05	0.8 ±0.1	0.65 ±0.1	0.85 ±0.1	1.25 ±0.1	0.85 ±0.15	1.25 ±0.15	1.6 ±0.2	1.25 ±0.2	1.6 ±0.2	2.0 ±0.2	2.5 ±0.2	1.25 ±0.2	1.6 ±0.2	2.0 ±0.2	2.5 ±0.2	1.6 ±0.2	2.0 ±0.2	2.5 ±0.2		
C	SL	50V	-	0.5~ 240	0.5 ~ 1000	0.5 ~1000	1100 ~ 1500	1600~ 2700	0.5 ~ 2700	3000~ 5600	6200~ 8200	-	-	-	-	-	-	-	-	-	-	-		
	с, тс	25V	0.5~ 47	0.5~ 220	0.5 ~ 1000	-	-	3300~ 8200	1500~ 3600	3900~ 6800	7500~ 10000	-	-	-	-	-	100000	-	-	-	-	-		
АРСЕ (рғ)	C, TC (Except SL,UJ)	50V	-	0.5 ~ 180	0.5 ~ 1000	0.5 ~ 560	620~ 1000	1100~ 3300	0.5 ~ 2200	2400~ 4700	-	560~ 10000	11000 22000	24000~ 47000	-	1000~ 13000		24000~ 47000	62000~ 68000	43000	93000	130000		
		6.3V	10	220	2200	-	-	10000	-	-	10000	-	-	-	22000	-	-	-	47000	-	-	47000		
		10V	10	100	1000	-	-	2200	-	-	4700~ 10000	-	-	-	22000	-	-	-	-	-	-	47000		
	A (X5R)	16V	-	47	330~ 470	-	-	1000	-	-	4700	-	-	-	6800~ 10000	-	-	-	-	-	-	-		
			25V	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	
		50V	-	6.8~ 10	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-		
C A P A		6.3V	0.1~ 10	47~ 100	470~ 1000	-	-	1000	-	-	6800~ 10000	-	-	-	22000	-	-	-	-	-	-	-		
CAPACITANCE		10V	0.1~ 10	33~ 100	220~ 470	220~ 270	330~ 470	560~ 1000	-	1000~ 3300	4700	1500~ 2200	3300	3900~ 4700	-	-	-	-	22000	-	-	-		
	B (X7R)	16V	0.1~ 1	10~ 33	100~ 220	68~ 200	220~ 330	390~ 1000	330~ 680	1000~ 1500	2200~ 3300	1500~ 2200	3300	3900~ 4700	-	-	-	2200	-	-	-	-		
RANGE		25V	-	4.7~ 10	47~ 100	39~ 68	82~ 100	150~ 470	100~ 330	470~ 620	680~ 1000	680~ 1500	1800	2200	-	-	-	1000	-	-	-	10000		
E (nF		50V	-	0.22~ 4.7	0.22~ 100	0.22~ 39	47~ 100	220	1~ 150	220	390~ 1000	2.2~ 680	820~ 1000	-	-	10~ 1000	-	-	-	-	-	3300~ 4700		
÷		6.3V	10~ 100	-	2200	-	-	10000	-	-	-	-	-	47000	-	-	-	-	-	-	-	-		
		10V	-	220~ 330	100~ 1000	-	-	4700	-	4700	10000~ 22000	-	-	-	22000	-	-	-	-	-	-	100000		
	F (Y5V)	16V	-	10~ 220	100~ 1000	10~ 680	820~ 1000	1200~ 2200	1000~ 2200	2700~ 4700	10000	3300~ 6800	10000	15000	-	-	-	22000	-	-	-	-		
		25V	-	10~ 33	22~ 330	10~ 220	270~ 470	560~ 1000	470~ 1000	1200~ 2200	2700~ 3300	1000~ 3300	4700~ 10000	-	-	-	-	-	10000	-	-	-		
		50V	-	2.2~ 10	2.2~ 100	2.2~ 68	82~ 150	180~ 1000	10~ 470	560~ 1000	-	100~ 1000	-	-	-	-	-	-	10000	-	-	-		

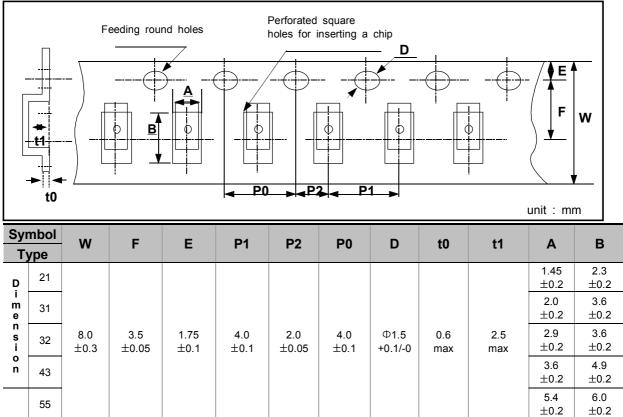
PACKAGING

CARDBOARD PAPER TAPE



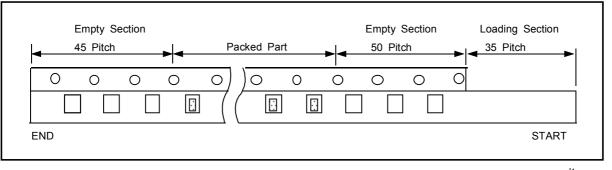
Symbol Type		w	F	Е	P1	P2	P0	D	t	Α	В	
	03				2.0	2.0 ±0.05	4.0 ±0.1			0.37 ±0.03	0.38 ±0.03	0.68 ±0.03
D i m	05			1.75 ±0.1	±0.05			Ф1.5 +0.1/-0	0.6 ±0.05	0.65 +0.05/-0.1	1.15 +0.05/-0.1	
e n	10	8.0 ±0.3	3.5 ±0.05			2.0 ±0.05				1.1 ±0.2	1.9 ±0.2	
s i o n	21				4.0 ±0.1				1.1 MAX	1.6 ±0.2	2.4 ±0.2	
n	31									2.0 ±0.2	3.6 ±0.2	

EMBOSSED PLASTIC TAPE



SAMSUNG ELECTRO-MECHANICS

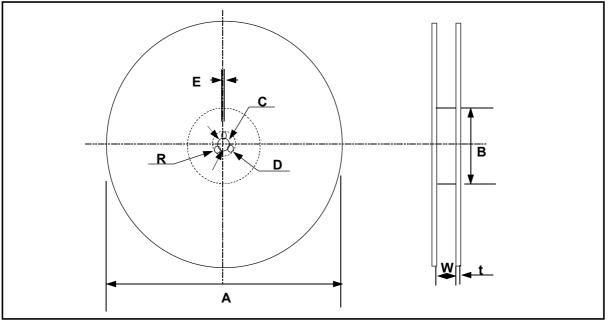
• TAPING SIZE



unit : pcs

Symbol	Cardboard Paper Tape	Embossed Plastic Tape
7" Reel	4000	2000
13" Reel	15000	-

• REEL DIMENSION



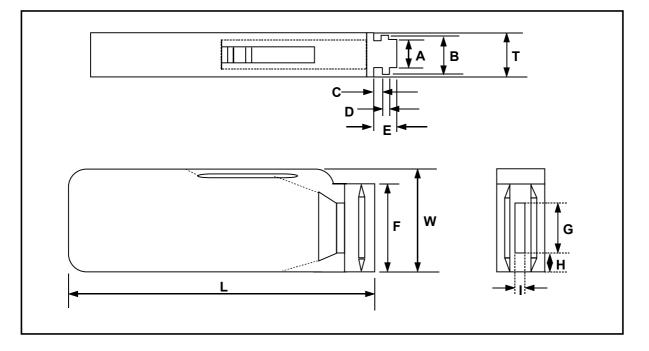
unit	mm

Symbol	Α	В	С	D	E	W	t	R
7" Reel	φ178±2.0	min.¢50						
13" Reel	φ330±2.0	min.¢70	φ13±0.5	21±0.8	2.0±0.5	10±1.5	0.8±0.2	1.0



BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	4.7±0.1

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

QUANTITY

Size	05(0402)	40(0602)	21(0	805)
Size	05(0402)	10(0603)	T≤0.85mm	T≥1.0mm
Quantity	50,000	10,000~15,000*	10,000	5,000

* Option



CHARACTERISTIC MAP

• CLASS I

Temperature Characteristics	Size	Voltage				Сар	acitance	Range (P	F)		
Characteristics	0.20	Tonago	0.5	10 1	100 1	000 1	0000 100	000 1000	000 100	00000	10000000
	05 (0402)	50V			240						
	10 (0603)	50V				1000					
SL,UJ	21 (0805)	50V				2700					
	31 (1206)	50V					8200				
	03 (0201)	25V		47							
	05	25V			220						
	(0402)	50V			180						
		25V				1000					
	(0603)	50V				1000					
	21	25V			33	00	8200				
C(COG) &	(0805)	50V				3300					
C(COG) & TC Series	31	25V			15	500	10000				
	(1206)	50V				4700	כ				
	32	50V			560		470	00			
	(1210)	100V				4700	18000				
	43	25V						100000			
	43 (1812)	50V			1000		680	000			
	55 (2220)	50V				43	000	130000			

● CLASS II , A(X5R)

Temperature Characteristics	Size	Voltage			ſ	Capacita	nce Ran	ge (^{pF})			
onaracteristics			10	100) 10	00 100	00 100	000 100	0000 100	00000 10	0000000
	0603	6.3V					■ 10000	 			
	(0201)	10V					1 0000	 			
		6.3V						22000	0		
	1005	10V						1 00000) 		
	(0402)	16V					■ 4700	0			
		50V				6800	10000				
		6.3V							22000	00	
	1608 (0603)	10V							■ 100000	0	
		16V					330	000 🗖 470	000		
		6.3V								■ 100000	00
A(X5R)	2012 (0805)	10V							22000	 00	
		16V							■ 100000	0	
		6.3V								= 100000	00
	3216 (1206)	10V						4700	000	10000000))
		16V							■ 470	0000	
		6.3V								220000	000
	3225 (1210)	10V								220000	000
		16V						680	00000	10000000)
	4532 (1812)	6.3V								■ 4700	00000
	5750	6.3V								■ 4700	00000
	(2220)	10V								■ 4700	00000



• CLASS II, B(X7R)

Temperature Characteristics	Size	Voltage		(Capacita	nce Ran	ge (^{pF})			
Characteristics	0120	Voltage	10 10	0 10	00 100	000 100	000 100	0000 1000	00000 10	0000000
		6.3V	100			10000				
	03 (0201)	10V	100			10000				
		16V	100		1000					
		6.3V			47	000	100000			
		10V			330	00	100000			
	05 (0402)	16V			10000	33000)			
	(***=)	25V		4	700	10000				
		50V	22	20	4700					
		6.3V				47	0000	1000000		
		10V				2200	00 🔳 470	000		
	10 (0603)	16V				100000	220000)		
B(X7R)		25V			47	000	100000			
		50V	22	0			100000			
		6.3V						1 00000	0	
		10V				22000	00	1000000		
	21 (0805)	16V				68000		1000000		
		25V				000	4700	00		
		50V	22	0			220000			
		6.3V					680	0000	1000000	0
		10V					1000000	4700	000	
	31 (1206)	16V				3300	00	33000		
	(1200)	25V				100000		1000000		
				1000						
		50V		1000				1000000		

\bullet class ${\rm I\!I}$, B(X7R)

Temperature Characteristics	Size	Voltage				Capacita	nce Ran	ge (^{pF})			
Characteristics	5120	Voltage	10	10	0 10	00 100	000 100	000 100	0000 1000	00000 100	000000
		6.3V								220000	00
		10V						150000	0 💶 470	0000	
	32 (1210)	16V						150000	0 💶 470	0000	
		25V					6	80000	220000	0	
		50V			220	0			1000000	1	
B(X7R)		10V								220000	00
	43	16V							220000	0	
	(1812)	25V							1 00000	0	
		50V				10000			1000000		
55	55	25V								1 00000	00
	55 (2220)	50V						33000	00 🔲 470	0000	

Multilayer Ceramic Capacitor ● CLASS II , F(Y5V)

Temperature Characteristics	Size	Voltage				Capa	citance F	Range (P	F)		
Characteristics		Tonaye	10	1(00 10	000 100	000 100	000 100	0000 1000	00000 10	0000000
	03 (0201)	6.3V				10000		100000			
		10 V					220000	33000	0		
	05	16 V				10000		220000			
	05 (0402)	25 V				10000	33000)			
		50 V			220	0	10000				
		6.3V							22000	00	
		10 V					100000		1000000		
	10 (0603)	16 V					100000		1000000		
		25 V				2200	0	3 30000			
		50 V			220	0		100000			
		6.3V								1 00000	00
		10 V							4 70	0000	
	21 (0805)	16 V				10000			220000	0	
		25 V				10000			1000000		
F(Y5V)		50 V			220	0			1000000		
		10 V						470	0000	220000	20
	04	16 V						1000000		10000000)
	31 (1206)	25 V					470	000	33000	000	
		50 V				10000			1000000		
		6.3V								470	00000
		10 V								22000	
	32 (1210)	16 V						33000	00	1500000	
	(1210)	25 V						1000000		1000000	
		50 V					100000		1000000		
		16V								22000	000
	43 (1812)	25 V								1 00000	
	(1012)	50 V								1 00000	
	55	10 V									1 00000
	(2220)										100000

SAMSUNG ELECTRO-MECHANICS

RELIABILITY TEST DATA

NO	ITE	м		PERFORM	ANCE			TEST CONDITION	
1	APPEAF	RANCE	NO ABNORI	MAL EXTERIOR	APPEARANCE		THROUGH MIC	ROSCOPE(×10)	
2	INSULA RESIST		SMALLER (RATED VO	R 500MΩ·μF PROD LTAGE IS BELOV DR 100MΩ·μF)		R IS		GE SHALL BE APPLIE T TIME IS 60 ~ 120 R	
3	WITHSTA VOLTA			TRIC BREAKDOV AL BREAKDOWN	VN OR		CLASS II :250% C	OF THE RATED VOLTAG OF THE RATED VOLTAG TH LESS THAN 50 ^{mA} CU	E FOR 1~5 SEC
							CAPACITAN	CE FREQUENCY	VOLTAGE
		CLASS I		IIN THE SPECIFIED			1,000pF AN	D 1\\\\\\\\\\\tag{1}10\%	0.5 5 1/100
4	CAPACIT	1	TOLERA	RANCE			MORE THA 1,000pF	N 1㎢±10%	– 0.5 ~ 5 Vrms
	ANCE						CAPACITAN	CE FREQUENCY	VOLTAGE
		CLASS	WITHIN	HIN THE SPECIFIED			10µF AND BEL	-OW 1k批±10%	1.0±0.2Vrms
		П	TOLERA	NCE			MORE THA 10µF	N 120Hz±20%	0.5±0.1Vrms
								CE FREQUENCY	VOLTAGE
5	Q	CLASS I	OVER 30pF LESS THAN	: Q ≥1,000 30pF: Q ≥400 +	-20C		1,000pF AN BELOW	D 11112±10%	0.5 5 1/1-1-5
		1		(C : CAPACI	ITANCE)		MORE THA 1,000pF	N 1kHz±10%	– 0.5 ~ 5 Vrms
			1. CHAR :	В			CAPACITAN	CE FREQUENCY	VOLTAGE
			RATE	D VOLTAGE	DF SPEC		10µF AND BEL	_OW 1km±10%	1.0±0.2Vrms
				6.3V	0.05 max		MORE THAN	10μF 120 Hz ±20%	0.5±0.1Vrms
				10V	0.05 max			I	1
				16V	0.035 max				
				25V	0.025 max				
			50	DV 이상	0.025 max				
			2. CHAR :	F					
		01 4 0 0		6.3V	10V		16V	25V	50V
6	T an δ	CLASS ∐				0.09m	ax (C<220nF)		
		ш	1005	1005 - 0.125max		0.125n	nax (C≥220nF)	0.05max	0.05max
			1608	1608 0.16max 0.125max			0.09max	0.05max(C≦100nF)	0.05max
			2012	0.40mau	0.16max 0.125max		0.00	0.07max(C>100nF)	0.05
			2012 3216	0.16max 0.16max			0.09max 0.09max	0.07max 0.07max	0.05max 0.05max
								0.07max(C≤6.8µF)	
			3225	0.16max	0.125max		0.09max	0.09max(C>6.8µF)	0.05max
			4532	0.16max	0.16max		0.09max	-	-
			5750	0.125max					-

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CAPACITANCE TEMPERATURE COEFFICIENT	CLASS	CHARACTERI COG PH RH SH TH UL SL		MP. COEFFICIENT (PPM/℃) 0 ± 30 -150 ± 60 -220 ± 60 -330 ± 60	2 POINT MEA	TEST CONDITION METRICAL TOLERANCE APPLY TO ASUREMENT OF TEMPERATURE TEMPERATURE TEMPERATURE 25 ± 2		
TEMPERATURE	CLASS	COG PH RH SH TH UL		(PPM/℃) 0 ± 30 -150 ± 60 -220 ± 60 -330 ± 60	2 POINT MEA COEFFICIENT STEP 1	ASUREMENT OF TEMPERATURE T: ONE AT 25℃ AND AT 85℃ TEMPERATURE		
TEMPERATURE	CLASS	PH RH SH TH UL		-150 ± 60 -220 ± 60 -330 ± 60	STEP 1	TEMPERATURE		
TEMPERATURE	CLASS	RH SH TH UL		-220 ± 60 -330 ± 60	1			
		SH TH UL		-330 ± 60		25 ± 2		
COEFFICIENT		TH			2	H		
		UL			<u> </u>	MIN RATED TEMP \pm 2		
				-470 ± 60	3	25 ± 2		
		SL		-750 ± 120	4	MAX RATED TEMP \pm 2		
				+350 ~ -1000	525 ± 2			
TEMPERATURE CHARACTERISTIC S	CLASS	CAPACITANCE CHANGE CHAR. CAP. CHANGE(%) A,B ±15% F +22% ~ -82%			The change of capacitance should be got from the capacitance at 25°C. After capacitance measured from Min. Temp. to Max. Temp., it should be calculated from the formula below $\frac{C2 - C1}{C1} \times 100 \%$ C1 : CAPACITANCE AT STANDARD TEMPERATURE(25°C) C2 : CAPACITANCE AT EACH TEMPERATURE			
ADHESIVE S OF TERMI		NO INDICAT OCCUR ON ELECTRODI	THE TERI	eeling Shall Minal	A 500g.f PRESSURE SHALL BE APPLIED FOR 10±1 SECOND.			
	APPEARANCE	NO MECHA	NICAL DAM	MAGE SHALL	BENDING SH	ALL BE APPLIED TO		
		OCCUR.			-	nm) WITH 0.3mm/SEC.		
		CHARA	CTER	CHANGE OF CAPACITANCE		EST BOARD AT THE LIMIT POINT HEN MEASURE CAPACITANCE.		
BENDING		CLAS	IS I	WITHIN $\pm 5\%$ OR \pm 0.5 pF WHICHEVER IS LARGER	CHARACTE C, A, B,			
BENDING STRENGTH	CAPACITANCE		A,B	WITHIN ±12.5%	50			
		CLASS II	F					
		STRENGTH	BENDING STRENGTH CAPACITANCE	STRENGTH CAPACITANCE A,B	BENDING STRENGTH CAPACITANCE CAPACITANCE CLASS I A,B WITHIN ±12.5%	BENDING STRENGTH CAPACITANCE		

NO	ITE	M		PERF	ORMANCE			TEST CO	ONDITION	
			MORE THA	N 75%	OF THE TERMINAL	SC	OLDER T	EMPERATUR	E : 230±5℃	
			SURFACE I	s то в	E SOLDERED NEWLY,	DI	P TIME	: 3±1 Sec		
			SO METAL	PART [DOES NOT COME	s	OLDER	: H63A		
			OUT OR DI	SSOLVE	Ξ	FL	LUX	: RMA TYPE		
			/	/		*P	*PB-FREE			
11	SOLDER	ABILITY	│ → /		/ //	sc	SOLDER TEMPERATURE : 260±5℃			
							SOLDER : Sn96.5-3Ag-0.5Cu			
							Flux : RMA TYPE			
					, MORE THAN 95% SURFACE IS TO BE		DIP TIME : 3±0.1Sec * PRE-HEATING : AT 80~120℃ FOR 10~30SEC.			
			SOLDERED				PRE-REP	TING . AT 80	~120 C FOR	10~30SEC.
			NO MECHANICAL DAMAGE			DI	P : SOLI	DER TEMPER	ATURE OF	
		APPEARANCE	SHAL	L OCCL	JR		270±	:5℃		
			CHARACTE	RISTIC	CAP. CHANGE	DI	PTIME	:10±1 SEC.		
					WITHIN ±2.5% OR	EA	ACH TER	MINATION SH	IALL BE FULL	Y
			CLASS	Ι	±0.25pF WHICHEVER	IM	IMMERSED AND PREHEATED			
		CAPACITANCE			IS LARGER	AS	S FOLLO	WING:		
	DEGISTANOE			A,B	WITHIN ±7.5%][OTED		TIME	
12	RESISTANCE		CLASS II	F	WITHIN ±20%		STEP	TEMP.(℃)	(SEC.)	
12	HEAT	Q	30pF AND C	OVER :	Q≥ 1000		1	80~100	60	
		CLASS I	LESS THAN	1 30 pF	: Q≥ 400+20×C		2	150~180	60	
	_	Ταn δ	TO SATISF	Y THE S	SPECIFIED	M	EASURE	AT ROOM TE	EMP. AFTER	-
		CLASS II	INITIAL VAL	UE			OOLING	FOR		
		INSULATION	TO SATISF		SPECIFIED		CLAS	$SI : 24 \pm 2$	HOURS	
		RESISTANCE	INITIAL VAL	UE			CLASS II : 48 \pm 4 HOURS			
		WITHSTANDING	TO SATISFY THE SPECIFIED							
		VOLTAGE	INITIAL VAL							
		APPEARANCE	NO MECHA OCCUR.	NICAL I	DAMAGE SHALL		BENDING SHALL BE APPLIED TO THE LIMIT(1mm) WITH 0.3mm/SEC.			
			CHARACTE		CAP. CHANGE	-			D AT THE LIN	IIT POINT
				RISTIC	WITHIN ±2.5% OR				URE CAPACIT	
					±0.25pF	Г	0114.5	EDEQUEN		
		CAPACITANCE	CLASS	Ι	WHICHEVER		CHAR.			
				1	IS LARGER		A,B,C,F	10HZ - 55	Hz → 10Hz	-
			CLASS	A,B	WITHIN ±5%	┤┝	CHAR.	TRAVER	SED TIME	-
13	VIBRATION		Ш	F	WITHIN ±20%		A,B,C,F	1	min	
	TEST	Q	30pF AND C			TH	HE ENTIF	RE FREQUEN	CY RANGE,	
		CLASS I		-	Q≥ 400+20×C	F	ROM 10	TO 55Hz ANI	D RETURN	
		Tanδ			SPECIFIED			SHALL BE TR	AVERSED	
		CLASS II	INITIAL VA	LUE		IN	1 MINU	TE.		
						 			PERFORMED	
		INSULATION	TO SATISF	Y THE	SPECIFIED					
		RESISTANCE	INITIAL VALUE			2 HOURS IN EACH THERE MUTUALLY PERPENDICULAR DIRECTION,				
						FOR TOTAL PERIOD OF 6 HOURS.				

* THE INITIAL VALUE OF HIGH DIELECTRIC CONSTANT SERIES SHALL BE MEASURED

AFTER THE HEAT TREATMENT OF 150 +0/-10 $^\circ$, 1Hr and sitting of 48 \pm 4hr at room temperature & room humidity.



NO		ſEM			PERFORM				TEST CONDITION				
NO													
		APPEARANCE											
			CHARAC	IERIST			E CHAN	IGE		HUMIDITY:90~95 %RH 5 : 500 +12/-0 Hr.			
						±5%				500 +12/-0 111.			
		CAPACITANCE	CLAS	SS I	-	WHICH	EVER		MEASURE	AT ROOM TEMPERATURE			
				1	IS LAR				AFTER COOLING FOR				
			CLASS	A,B	WITHIN	1 ±12.5	%		CLASS I :				
			П	F	WITHIN	l ±30%			CLASS II :	CLASSⅡ : 48±4 Hr.			
		Q	30pF ANE	30pF AND OVER : Q ≥ 350									
	HUMIDITY	CLASS I	10 ~30 pF		≥ 275 + 2.				6.3V	0.125 MAX *Condition			
14	(STEADY		LESS TH	AN 10pF	: Q≥ 200	+ 10×0	2		Tanδ				
	STATE)		CHAR.	25V AND	16V	10V	6.31/	4V		1005 C ≥0.22µF			
			CHAR.	OVER	100	100	10V 6.3V 4V			1608 C ≥2.2µF			
		Tanδ	A,B	0.05	0.05 MAX	0.05 MAX	0.075 MAX	0.1 MAX	CLASS II	2012 C \geq 4.7 μ F			
		CLASS II			0.1MAX	IVIAA	IVIAA	IVIAA	(A,B)	3216 C ≥10.0µF			
			F	0.075	0.1MAX (C ≦1.0µF) 0.125	0.15	0.195	0.25	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				
				MAX	MAX (C≥1.0μF)	MAX	MAX	MAX		$4332 \text{ C} = 47.0 \mu\text{I}$ 5750 C $\geq 100.0 \mu\text{F}$			
					. ,					0100 0 - 100.0pi			
		INSULATION			TION RESI								
		RESISTANCE			2∙μF PRODU	ICT WH							
			SMALLER	{						17405			
		APPEARANCE	NO MECHANICAL DAMAGE SHALL OCCUR						APPLIED VO	LTAGE : ATED VOLTAGE			
			CHARACTERISTIC CAPACITANCE CHANGE							TEMPERATURE : 40±2 ℃			
										UMIDITY:90~95%RH			
			$\begin{array}{c} \text{WITHIN } \pm 7.5\% \text{ OR} \\ \text{CLASS I} \qquad \pm 0.75 \text{pF WHICHEVER} \end{array}$					TEST TIME : 500 +12/-0 Hr.					
			CLA	ASS I ±0.75pF WHICHEVER			CURRENT APPLIED : 50mA MAX.						
					IS LAR								
				A,B	WITHIN	1 ±12.5	%						
		CAPACITANCE			WITHIN	l ±30%				JE AFTER BE HEAT-TREATED N 150℃+0/-10℃ AND BE LEFT			
					WITHIN	+30~-	40%			R AT ROOM TEMPERATURE.			
			CLASS		1005 C	>0.47µF			<latter me<="" td=""><td>EASUREMENT></td></latter>	EASUREMENT>			
			П	F	1608 C	>1.0µF			CLASS I SH	OULD BE MEASURED AFTER			
					2012 C	> 4.7 µF				4±2 HRS IN ROOM			
45	MOISTURE				3216 C	>10.0µF			-	RE AND HUMIDITY.			
15	RESISTANCE				3225 C	>22.0µF				HOULD BE MEASURED			
					4532 C	> 47.0 µF				ED FOR 1 HR IN 150℃+0/-10			
		Q			: Q≥ 200				C AND BE I	LEFT FOR 48±4HR AT ROOM			
		CLASS I	30pF AND	BELOV	V : Q≥ 100	+ 10/3	3×C		TEMPERATU	RE.			
			CHAR.	25V AND	16V	10V	6.3V	4V	6.3V Tanδ	0.125 MAX *Condition			
				OVER						1005 C ≥0.22 <i>μ</i> F			
		Tanõ	A,B	0.05 MAX	0.05 MAX	0.05 MAX	0.075 MAX	0.1 MAX		1608 C ≥2.2μF			
		CLASS II						$\left - \right $	CLASSI	2012 C ≥4.7µF 3216 C ≥10.0µF			
			F	0.075	0.1MAX (C ≦1.0μF)	0.15	0.195	0.25	(A,B)	3225 C ≥22.0,4 ⁷			
			$\left \begin{array}{cccc} F & 0.0125 \text{ MAX} & 0.125 \text{ MAX} \\ MAX & 0.2125 \text{ MAX} \\ (C \ge 1.0/dF) \end{array}\right \text{MAX} \text{MAX} \text{MAX}$						4532 C ≥47.0, <i>d</i> [∓]				
			MINIMUM	INSULA	TION RESI	STANCI	=:		1 L	5750 C ≥100.0⊭ [¯]			
		INSULATION	MINIMUM INSULATION RESISTANCE: 500 M Ω OR 25M Ω · μ F PRODUCT,										
		RESISTANCE	WHICHE	ER IS S	SMALLER.								
<u> </u>	1	1							1				

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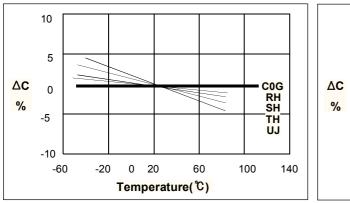
NO	ITE	M		F	PERFORM							DITION	
		APPEARANCE	NO MECH	IANICAL	DAMAGE	E SHALI	- OCCU	IR	TEST T	200% ME:	OF RATED 1000 +48/-0 PLIED : 50m	Hr.	
			CHARAC	TERISTIC		CAP.	CHANG	=		CLAS	S I	125 ±3 ℃	
			CLAS		WITHI	N ±3%	OR ±0	. 3 pF,	_	ASS	A B	85 ±3 ℃ 125 ±3 ℃	
				A,B	-	HEVER		JER		1	F	85 ±3 ℃	
				А,В		N ±12.3			<initial< td=""><td>. MEA</td><td>SUREMENT></td><td></td></initial<>	. MEA	SUREMENT>		
16	HIGH	CAPACITANCE	CLASS II F		WITHI 1005 1608 2012 3216	WITHIN+30~40% 1005 C>0.47µF 1608 C>1.0µF 2012 C>4.7µF 3216 C>10.0µF 3225 C>22.0µF		- CLASS II SHOULD BE MEASURED INITIAL VALUE AFTER BE HEAT-TREATED FOR 1 HR IN 150℃+0/-10℃ AND BE LEFT FOR 48± 4HR AT ROOM TEMPERATURE. <latter measurement=""> CLASS I SHOULD BE MEASURED AFTER LEFT FOR 24±2 HRS IN ROOM TEMPERATURE AND HUMIDITY.</latter>					
	RESISTANCE				4532	C>47.0µ	F		CLASS II SHOULD BE MEASURED LATTE				
		Q CLASS I	10 ~ 30 1	30 pF AND OVER : Q ≥ 350 10 ~ 30 pF : Q ≥ 275 + 2.5×C LESS THAN 10pF :Q ≥200 + 10×C					VALUE AFTER BE HEAT-TREATED FOR 1 HR IN 150℃+0/-10℃ AND BE LEFT FOR 48= 4HR AT ROOM TEMPERATURE.				
		Tanδ CLASS ΙΙ	CHAR.	25V AND OVER	16V	10V	6.3V	4V			1005	zation Conditions $5 \text{ C>0.47} \mu \text{F}$ $3 \text{ C} \geq 2.2 \mu \text{F}$	
			A,B	0.05 MAX	0.05 MAX	0.05 MAX	0.075 MAX	0.1 MAX	CLAS (A,B		2012 3216	2 C ≥4.7μF C ≥10.0μF	
			F	MAX	0.1MAX (C<1.0,⊭F) 0.125MAX (C≧1.0,⊭F)	0.15 MAX	0.195 MAX	0.25 MAX			3225 C ≥22.0µF 4532 C ≥47.0µF 5750 C ≥100.0µF		
		INSULATION RESISTANCE	MINIMUM 1,000 MΩ WHICHEV	OR 50M	₽·μF PROE		CE:		(TWICE OF RATED VOLTAGE WILL BE APPLIED TO ALL SERIES BUT ABOVE) ** HOWEVER, A/B는1005 C ≥0.22µF				
		APPEARANCE	NO MECH		DAMAGE	- SHALI	0000	IR	SEE (F		S SHALL BI	E SUBJECTED	
			CHARAC			CAP.	CHANGI				CLES OF T JRE CYCLE	HE AS FOLLOWING	
			CLAS	s I		N ±2.59		VER IS	STEP		TEMP.(℃)	TIME(MIN)	
		CAPACITANCE		1	LARG	ER	-		. 1		/IN.RATED	30	
17	TEMPERATURE		CLASS	A,B F	_	N ±7.59 N ±20%			2		25	2~3	
17	CYCLE	Q CLASS I	30 pF AN LESS TH∕	D OVER	: Q ≥	1000	-		3		IAX.RATED	30	
		Tanδ	TO SATIS	-					4		25	2~3	
		CLASS II	INITIAL V						MEASU	RE A	T ROOM T	EMPERATURE	
		INSULATION RESISTANCE	TO SATISFY THE SPECIFIED INITIAL VALUE						AFTER COOLING FOR CLASS I : 24±2 Hr. CLASS II : 48±4 Hr.				

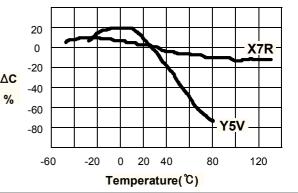


CAPACITANCE - TEMPERATURE CHARACTERISTICS

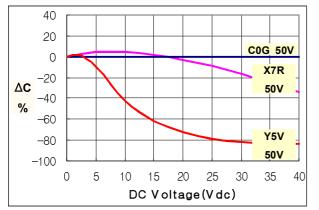
CHARACTERISTIC GRAPH

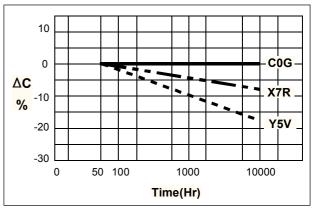
• ELECTRICAL CHARACTERISTICS



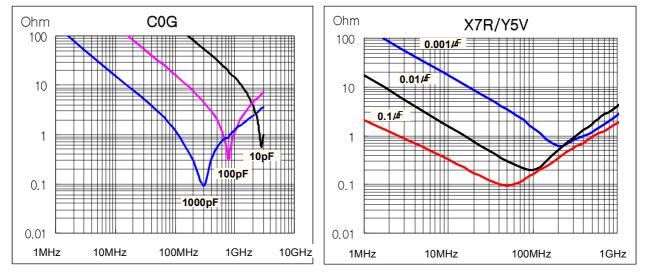


► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





▶ IMPEDANCE - FREQUENCY CHARACTERISTICS



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APPLICATION MANUAL

• Storage Condition

Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40° C and 70%, respectively. Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

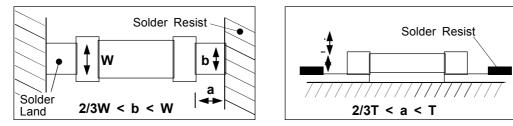
Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

• Design of Land Pattern

When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor. The amount of solder at the end terminations has a direct effect on the crack. The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently. Use the following illustrations as guidelines for proper land design. Recommendation of Land Shape and Size



Adhesives

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

They should not spread or run when applied to the circuit board.

They should harden quickly.

They should not corrode the circuit board or chip material.

They should be a good insulator.

They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.

Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at 160° C or less, within 2 minutes or less.

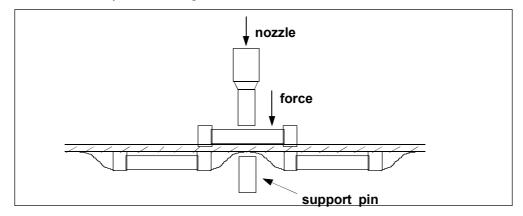
Mounting

► Mounting Head Pressure

Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.

Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side, it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



• Flux

Although the solderability increased by the highly-activated flux, increase of activity in flux may also degrade the insulation of the chip capacitors. To avoid such degradation, it is recommended that a mildly activated rosin flux(less than 0.2% chlorine) be used.



• Soldering

Since a multilayer ceramic chip capacitor comes into direct contact with melted solder during soldering, it is exposed to potentially mechanical stress caused by the sudden temperature change. The capacitor may also be subject to silver migration, and to contamination by the flux. Because of these factors, soldering technique is critical.

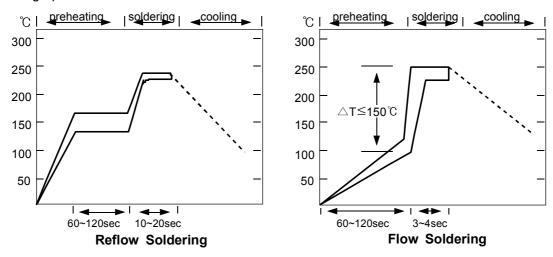
Soldering Methods

Method		Classification
Reflow	- Overall heating	Infrared raysHot plateVPS(vapor phase)
soldering	- Local heating	- Air heater - Laser - Light beam
Flow soldering	- Single wave - Double wave	-

* We recommend the reflow soldering method.

Soldering Profile

To avoid crack problem by sudden temperature change, follow the temperature profile in the adjacent graph.



Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors. The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor. Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

Amount of Solder

Too much Solder	Cracks tend to occur due to large stress
Not enough Solder	Weak holding force may cause bad connections or detaching of the capacitor
Good	

Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference($\triangle T$) must be less than 100 °C

6-6. Cleaning

If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending of the circuit board.



CROSS REFERENCE

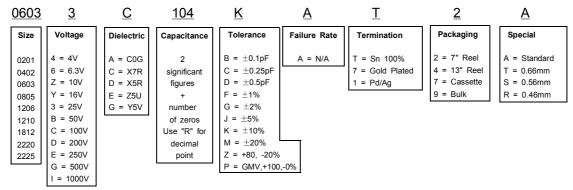
P/N	COMPANY	SAMSUNG	AVX	JOHANSON	KEMET	KYOCERA	MURATA	NOVACAP	PANASONIC	ROHM	TAIYO - YUDEN	TDK	VITRAMON
COMPANY	MODEL(MLCC)	CL	-	-	С	СМ	GRM	-	ECJ	MCH	МК	С	VJ
	0201(0603)	03	-	-	-	03	33	-	z	-	063	0603	-
	0402(1005)	05	0402	R07	0402	05	36	0402	0	15	105	1005	0402
	0603(1608)	10	0603	R14	0603	105	39	0603	1	18	107	1608	0603
	0805(2012)	21	0805	R15	0805	21	40	0805	2	21	212	2012	0805
② SIZE (EIA/JIS)	1206(3216)	31	1206	R18	1206	316	42-6	1206	3	31	316	3216	1206
	1210(3225)	32	1210	S41	1210	32	42-2	1210	4	32	325	3225	1210
	1808(4520)	42	1808	R29	1808	42	-	1808	-	-	-	4520	1808
	1812(4532)	43	1812	S43	1812	43	43-2	1812	-	43	432	4532	1812
	2220(5750)	55	-	-	2220	55	44-1	2221	-	-	550	5650	-
	COG(NPO)	с	A	N	G	CG	COG/CH	N	с	A	с	COG/CH	А
	P2H(N150)	Р	s	-	-	Р	P2H	-	Р	-	Ρ	PH	-
	R2H(N220)	R	1	-	-	R	R2H	-	R	-	R	RH	-
	S2H(N330)	s	3	-	-	s	S2H	-	S	-	S	SH	
TEMPERATURE CHARACTERISTIC	T2H(N470)	т	0	-	-	т	T2H	-	т	-	Т	TH	-
	U2J(N750)	U	z	-	-	U	U2J	-	U	UJ	U	UJ	-
	S2L	L	Y	-	-	SL	SL	-	G	SL	SL	SL	
	X7R	в	с	w	R(X)	X7R	X7R	В	В	с	BJ	X7R(B)	Y(X)
	Z5U	E	E	z	U	-	Z5U	z	-	E	-	Z5U	U
	Y5V	F	G	Y	v	Y5V	Y5V	Y	F	F	F	Y5V	-
NOMINAL CAPACITANCE				EX	() 103=10,0	00pF 221=	220pF 225	5=2,200,000pF=:	2.2 ^{µF} 1R5=1.	5pF 010=1	pF		
⑤ CAPACITAN	CE TOLERANCE			B:±0.1 ^{pF} C:	±0.25 ^{pF}	D:±0.5pF F	:±1% G:±	:2% J:±5%	K:±10%	M:±20%	Z:-20~+80%		
	6.3V	Q	6	-	9	06	6.3	-	0J	-	J	OJ	-
	10 V	Р	z	100	8	10	10	-	1A	4	L	1A	-
	16 V	0	Y	160	4	16	16	160	1C	3	E	1C	J
	25 V	А	3	250	3	25	25	250	1E	2	т	1E	х
	50 V	В	5	500	5	50	50	500	1H	5	U	1H	А
	100 V	с	1	101	1	100	100	101	2A	1		2A	В
RATED	200V	D	2	201	2	200	200	201	2D	-		-	С
VOLTAGE	250V	E	v	-	-	250	250	251	-	-		2E	-
	500V	G	7	501	-	500	500	501	-	-		-	E
										-	-	2J	-
	630V	н	-	-	-	630	630	-	-				
	630V 1000V	H	- A	- 102	-	630 1000	630 1K	- 102	-	-	-	ЗA	G
										-	-	3A 3D	G -
	1000V	I	A	102	-	1000	1К	102	-				
	1000V 2000V	J	A	102 202	-	1000 2000	1К 2К	102 202	-	-	-	3D	-
	1000V 2000V 3000V	I J K	A G H	102 202	-	1000 2000 3000	1К 2К 3К	102 202 302	-	-	-	3D 3F	- Н
⑦ TERMINATION	1000V 2000V 3000V 4000V	і Ј К	A G H J	102 202 302	-	1000 2000 3000 4000	1К 2К 3К -	102 202 302 402	-	-	-	3D 3F -	- Н
⑦ TERMINATION	1000V 2000V 3000V 4000V NICKEL BARRIER	I J - N	A G H J T	102 202 302 V	- - - C	1000 2000 3000 4000 A	1K 2K 3K - (GRM)	102 202 302 402 N		- - (MCH)	-	3D 3F - -	- H - X
	1000V 2000V 3000V 4000V NICKEL BARRIER Ag/Pd	I J K - N P	A G H J T 1	102 202 302 V -	- - - - C	1000 2000 3000 4000 A B	1K 2K 3K - (GRM) (GR)	102 202 302 402 N P		- - (MCH) (MC)	-	3D 3F - -	- H - X F
© TERMINATION	1000V 2000V 3000V 4000V NICKEL BARRIER Ag/Pd BULK(VINYL)	I J K - N P B	A G H J T 1 9	102 202 302 V - (NONE)	- - - C -	1000 2000 3000 4000 A B B	1K 2K 3K - (GRM) (GR) PB	102 202 302 402 N P	- - - - - - X	- - (MCH) (MC) -	- - - - B	3D 3F - - - B	- H - X F B



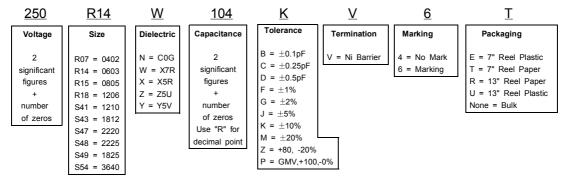
► SAMSUNG : CL10B104KA8NNNC

<u>CL</u>	<u>10</u>	<u>B</u>	<u>104</u>	K	A	<u>8</u>	<u>N</u>	<u>N</u>	<u>N</u>	<u>C</u>
Series	Size	Dielectric	Capacitance	Tolerance	Voltage	Thickness	Electrode/	Products	Special	Packaging
							Termination/			
	03 = 0201	C = COG	2	A = $\pm 0.05 pF$	Q = 6.3V	3 = 0.30	Plating	A = Array	Various	B = Bulk
	05 = 0402	P = P2H	significant	$B = \pm 0.1 pF$	P = 10V	5 = 0.50		(2-element)		P = Cassette
	10 = 0603	R = R2H	figures	C = $\pm 0.25 pF$	O = 16V	8 = 0.80	A = Pd/Ag/	B = Array		C = Paper 7"
	21 = 0805	S = S2H	+	$D = \pm 0.5 pF$	A = 25V	A = 0.65	Sn 100%	(4-element)		D = Paper 13"
	31 = 1206	T = T2H	number	$F = \pm 1\%$	B = 50V	C = 0.85	N = Ni/Cu/	C = High - Q		(10,000EA)
	32 = 1210	U = U2H	of zeros	G = ±2%	C = 100V	H = 1.60	Sn 100%	L = LICC		E = Embossing 7"
	43 = 1812	L = S2L	Use "R" for	$J = \pm 5\%$	D = 200V	I = 2.00	G = Cu/Cu/	N = Normal		F = Embossing 13"
	55 = 2220	B = X7R	decimal point	$K = \pm 10\%$	E = 250V	J = 2.50	Sn 100%	P = Automotive		L = Paper 13"
		A = X5R		$M = \pm 20\%$	G = 500V	L = 3.20		W = 3 terminal		(15,000EA)
		F = Y5V		Z = +80,-20%	H = 630V		,	chip		O = Paper 10"
					I = 1000V					S = Embossing 10"

AVX : 06033C104KAT2A



▶ JOHANSON : 250R14W104KV6T

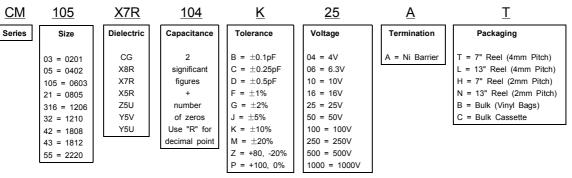


▶ KEMET : C0603C104K3RAC

<u>C</u>	<u>0603</u>	<u>C</u>	<u>104</u>	<u>K</u>	<u>3</u>	<u>R</u>	<u>A</u>	<u>C</u>
Series	Size	Specification	Capacitance	Tolerance	Voltage	Dielectric	Failure Rate	Termination
	0402 0603 0805 1206 1210 1812 2220 2225	C = Standard A = GR900 P = Mil-C-55681 CDR01-CDR06 N = Mil-C-55681 CDR31-CDR35 Z = Mil-C-123 E = Mil Equivalent (Group A Only)	2 significant figures + number of zeros Use "R" for decimal point	$B = \pm 0.1 pF$ $C = \pm 0.25 pF$ $D = \pm 0.5 pF$ $F = \pm 1\%$ $G = \pm 2\%$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$ $Z = +80, -20\%$ $D = \pm 400, -20\%$	9 = 6.3V 8 = 10V 4 = 16V 3 = 25V 5 = 50V 1 = 100V 2 = 200V	G = C0G R = X7R P = X5R U = Z5U X = BX(Mil) V = Y5V	A = Standard M = 1.0 (Mil) P = 0.1 (Mil) R = 0.01 (Mil) S = 0.001 (Mil)	C = Ni w/Tin Plate H = Ni w/Solder T = Silver G = Gold Plated
	2225		decimal point					



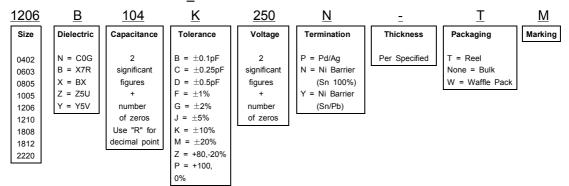
KYOCERA : CM105X7R104K25AT



MURATA : GRM188R71E104KA01D

<u>GRM</u>	<u>18</u>	<u>8</u>	<u>R7</u>	<u>1E</u>	<u>104</u>	<u>K</u>	<u>A01</u>	D
Series	Size	Thickness	Dielectric	Voltage	Capacitance	Tolerance	Individual Specification	Packaging
Ni Barrier	03 = 0201	3 = 0.3mm	5C = C0G	0J = 6.3V	2	$B = \pm 0.1 pF$	Code	D = 7" Reel Paper
L1	15 = 0402	5 = 0.5mm	R7 = X7R	1A = 10V	significant	C = ±0.25pF		L = 7" Reel Plastic
	18 = 0603	8 = 0.8mm	R6 = X5R	1C = 16V	figures	$D = \pm 0.5 pF$		J = 13" Reel Paper
	21 = 0805	A = 1.0mm	E4 = Z5U	1E = 25V	+	$F = \pm 1\%$		K = 13" Reel Plastic
	31 = 1206	B = 1.25mm	F5 = Y5V	1H = 50V	number	$G = \pm 2\%$		B = Bulk
	32 = 1210	C = 1.6mm		2A = 100V	of zeros	$J = \pm 5\%$		C = Bulk Cassette
	42 = 1808	D = 2.0mm		2E = 250V	Use "R" for	$K = \pm 10\%$		T = Bulk Tray
	43 = 1812	E = 2.5mm		2H = 500V	decimal	$M = \pm 20\%$		
	55 = 2220	F = 3.2mm		3A = 1000V	point	Z = +80,-20%		
	L					P = +100, 0%		

NOVACAP : 0603B104K250N_TM

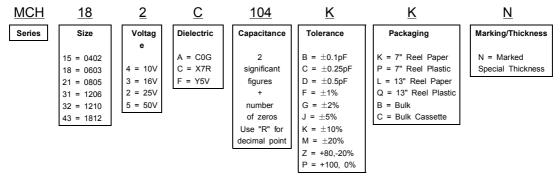


▶ PANASONIC : ECJ1EB1E104K

<u>ECJ</u>	<u>1</u>	E	<u>B</u>	<u>1E</u>	<u>104</u>	K
Series	Size	Packaging	Dielectric	Voltage	Capacitance	Tolerance
	Z = 0201 0 = 0402 1 = 0603 2 = 0805 3 = 1206 4 = 1210	X = Bulk E = Paper 2mm V = Paper 4mm F, Y = Plastic 4mm W = Large Reels 2mm Z = Large Reels 4mm C = Bulk Cassette	C = C0G B = X7R, X5R F = Y5V	0J = 6.3V 1A = 10V 1C = 16V 1E = 25V 1H = 50V 2A = 100V 2D = 200V	2 significant figures + number of zeros Use "R" for decimal point	$C = \pm 0.25 pF$ $D = \pm 0.5 pF$ $F = \pm 1\%$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$ Z = +80, -20%

SAMSUNG ELECTRO-MECHANICS

► ROHM : MCH182C104KKN



► TAIYO-YUDEN : TMK107BJ104K_T

T	M	<u>K</u>	<u>107</u>	<u>BJ</u>	<u>104</u>	<u>K</u>	=	T
Voltage	Туре	Termination	Size	Dielectric	Capacitance	Tolerance	Special	Packaging
$\begin{array}{l} A \;=\; 4V \\ J \;=\; 6.3V \\ L \;=\; 10V \\ E \;=\; 16V \\ T \;=\; 25V \\ U \;=\; 50V \end{array}$	M = Multilayer V = Hi Q	K = Ni Barrier	105 = 0402 $107 = 0603$ $212 = 0805$ $316 = 1206$ $325 = 1210$ $432 = 1812$ $550 = 2220$	CG = C0G CH = C0H CJ = C0J CK = C0K BJ = X5R, X7R F = Y5V	2 significant figures + number of zeros Use "R" for decimal point	$\begin{array}{l} C = \pm 0.25 p F \\ D = \pm 0.5 p F \\ F = \pm 1 \% \\ G = \pm 2 \% \\ J = \pm 5 \% \\ K = \pm 10 \% \\ M = \pm 20 \% \\ Z = +80, -20 \% \end{array}$	Various	T = Reel B = Bulk

▶ TDK : C1608X7R1E104KT

<u>C</u>	<u>1608</u>	<u>X7R</u>	<u>1E</u>	<u>104</u>	<u>K</u>	I
Series	Size	Dielectric	Voltage	Capacitance	Tolerance	Packaging
	0603 = 0201 1005 = 0402 1608 = 0603 2012 = 0805 3216 = 1206 3225 = 1210 4532 = 1812 5650 = 2220	CG X7R Z5U Y5V	0J = 6.3V 1A = 10V 1C = 16V 1E = 25V 1H = 50V	2 significant figures + number of zeros Use "R" for decimal point	$\begin{array}{l} C = \pm 0.25 p F \\ D = \pm 0.5 p F \\ F = \pm 1 \% \\ G = \pm 2 \% \\ J = \pm 5 \% \\ K = \pm 10 \% \\ M = \pm 20 \% \\ Z = +80, -20 \% \end{array}$	T = Reel B = Bulk

► VITRAMON : VJ0603Y104KXXMC

VJ	<u>0603</u>	<u>Y</u>	<u>104</u>	<u>K</u>	<u>X</u>	<u>X</u>	M	<u>C</u>
Series	Size	Dielectric	Capacitance	Tolerance	Termination	Voltage	Marking	Packaging
	0402 0603 0805 1206 1210 1812 2225	X = BX A,N = C0G Y = X7R U = Z5U H = X8R	2 significant figures + number of zeros Use "R" for decimal point	$B = \pm 0.1pF$ $C = \pm 0.25pF$ $D = \pm 0.5pF$ $F = \pm 1\%$ $G = \pm 2\%$ $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$ $Z = +80, -20\%$ $P = +100, 0\%$	X = Silver, Ni Barrier Tin Plated	J = 16V X = 25V A = 50V B = 100V C = 200V	M = Marking A = No Marking	C = 7" Reel Paper T = 7" Reel Plastic P = 13" Reel Paper R = 13" Reel Plastic B = Bulk